



Progress on investigation of dynamic vacuum (RF structures only)

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- Requirements from beam dynamics
- Static vacuum
- Dynamic vacuum
 - Breakdowns
 - Dark current
- Experimental approach
 - ESD measurements
 - Direct measurement
- Outlook and conclusions







 The dynamic vacuum threshold for preventing fast ion beam instability (essentially do to direct field ionization and not the usual impact ionization) is:

 H_2 and CO_2 partial pressures < 10⁻⁹ Torr

- This happens for practically all the main LINAC length, inside the RF accelerating structures
- For details see <u>G. Rumolo, J-B Jeanneret, D. Schulte</u> and <u>C. Garion (this workshop)</u>







- Several tools have been developed for the calculation of dynamic vacuum:
 - Thermal analogy implemented in FEM by Cedric Garion
 - Monte-Carlo simulations implemented in CASTEM (FEM code) by Cedric Garion (<u>CLIC09 Workshop</u>)
 - Electrical analogy implemented in PSpice, with conductance of single elements calculated by Monte-Carlo by Pedro Costa Pinto (<u>TS Workshop 08</u>)
 - Analytical models by Volker Ziemann (Uppsala University)

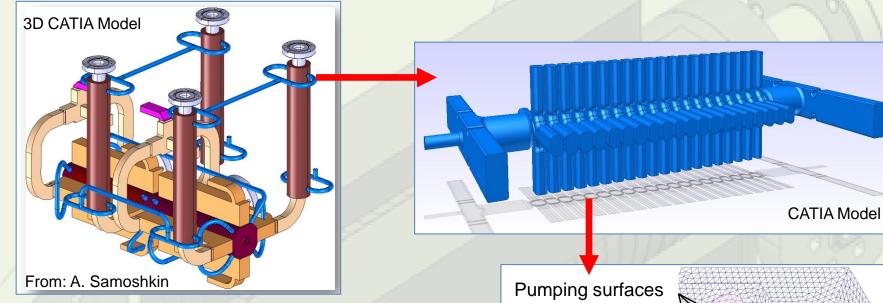
All tools have been crosschecked and agree within 10%





Static vacuum – thermal analogy

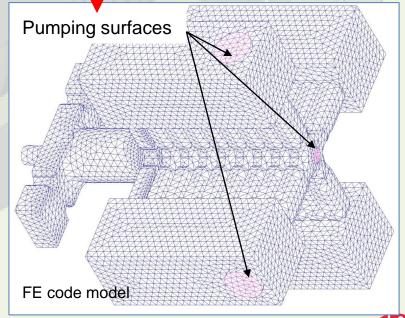




Calculations are based on the equivalence of vacuum and thermal conductances, which are evaluated by FE analysis, and using the following outgassing values (H_2O):

- 10⁻¹⁰ mbar.l.sec⁻¹cm⁻² for 100h pumping
- 10⁻¹¹ mbar.l.sec⁻¹cm⁻² for 1000h pumping

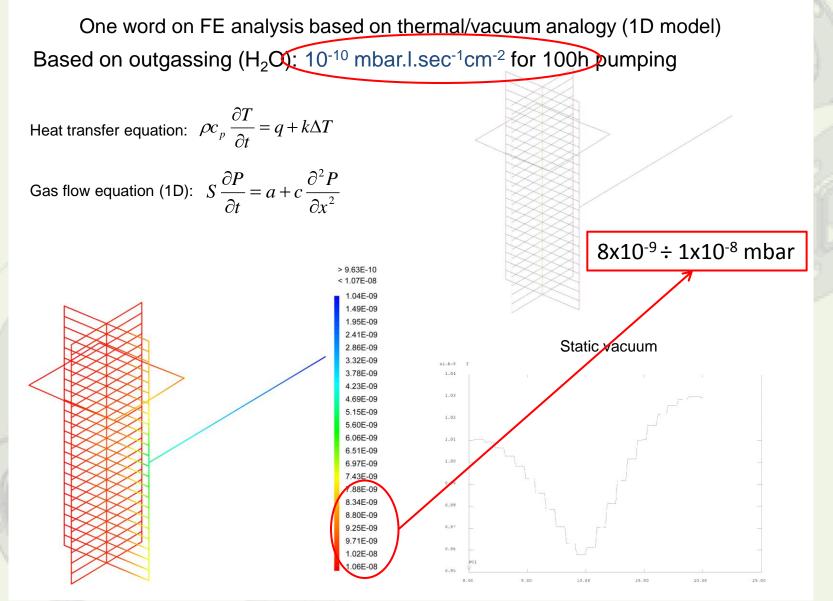
Does not take into account re-adsorpion





Static vacuum - Results



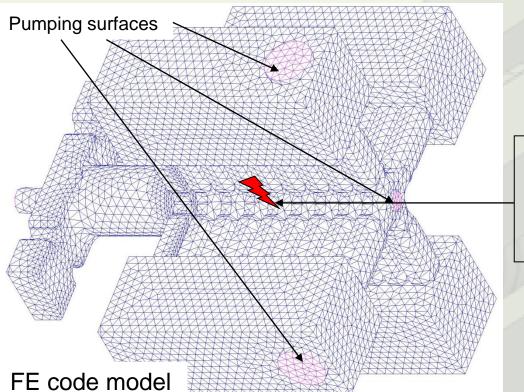






Dynamic vacuum I - Breakdown





2.10^{12} H₂ or CO molecules released during breakdown (in a baked system)

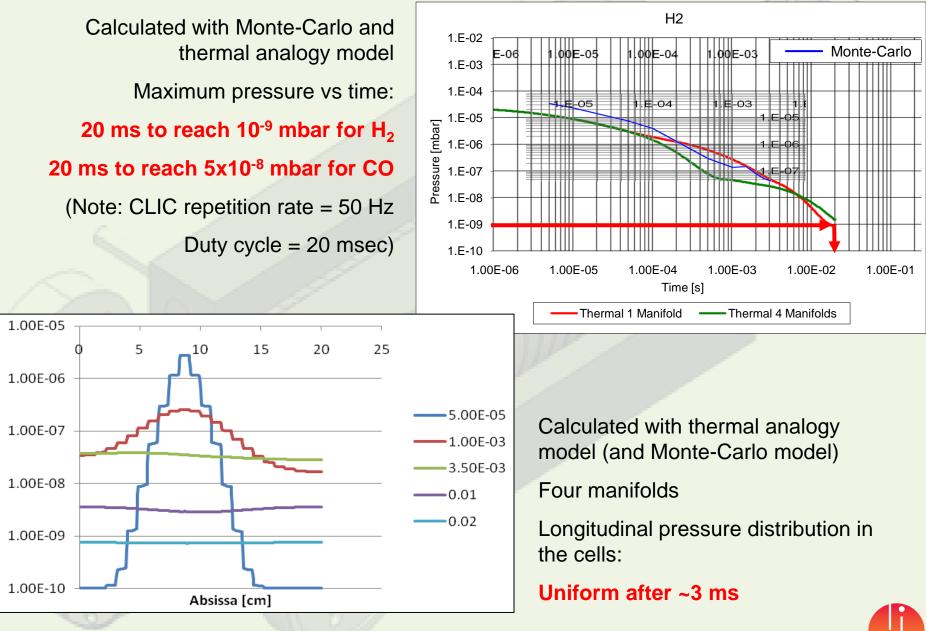
Data measured in DC "spark test" reported in PRST-AB12, 092001 (2009)





Dynamic vacuum I – Results





IWLC 2010

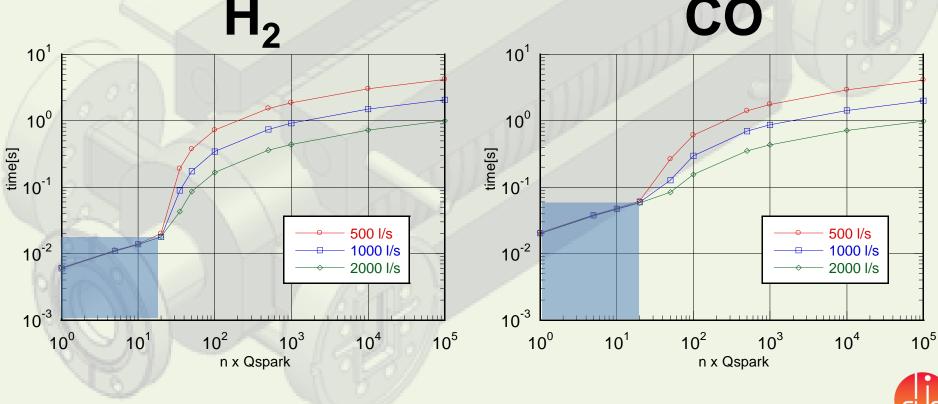
Pressure [mbar]



IWLC 2010

Dynamic vacuum I – Effect of a manifold

- Calculated recovery time to 10⁻⁸ mbar with PSpice for a quadrant type structure in a CTF2 type tank (old data)
- For one sparks outgassing Qspark, or multiples of it equal to n x Qspark
- Two regions: first is determined by the filling time of the cavity + tank volume
- Second is determined by the applied pumping speed







Dynamic vacuum II – Dark currents

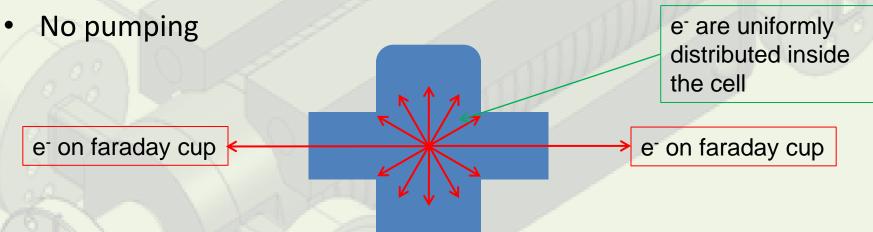
- Dynamic vacuum due to field emission: the problem
 - Electrons are field-emitted from high field regions in absence of a breakdown (dark current).
 - They hit the cavity wall releasing gas by Electron Stimulated Desorption (ESD)
 - Outgassed molecules are emitted with eV speeds, but after first collision they are thermalized and then travel <1 mm during the 200 ns RF pulse, thus cannot escape from RF structure.
 - Timescale of the order of the RF pulse duration: outgassing at the beginning of the pulse may affect bunches within the same train.
 - Very difficult to measure: we may have p>10⁻⁹ mbar locally during the 200 ns RF pulse (in all structures) in a small volume. When this is diluted and pumped through the conductance of the RF structure, it may not be measureble







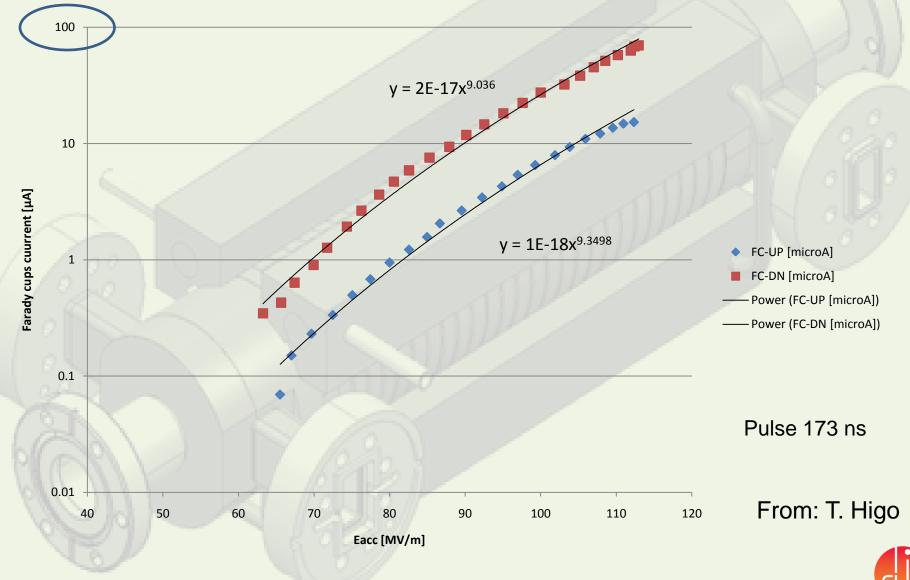
- Only one cell is modelled
- Electrons are field-emitted, then accelerated and distributed uniformly in the cell
- Dynamic vacuum by ESD: desorbed molecules fill the whole cell volume



| Cell [mm] | dimensions | outer area | beam area | copper area | cell volume [mm3] | beam channel [mm3] |
|-----------|------------|------------|-----------|-------------|----------------------|-----------------------|
| Ext diam | 20 | 1086.99 | 28.27 | 1030.44 | 2293.36 | 206.40 |
| Iris diam | 6 | 100 | £3,0// | | cell volume [liters] | beam channel [liters] |
| Length | 7.3 | 8 93 | e0/// | | 2.29E-03 | 2.06E-04 |



Faraday cup measurements - T18_VG24_Disk_2 - KEK

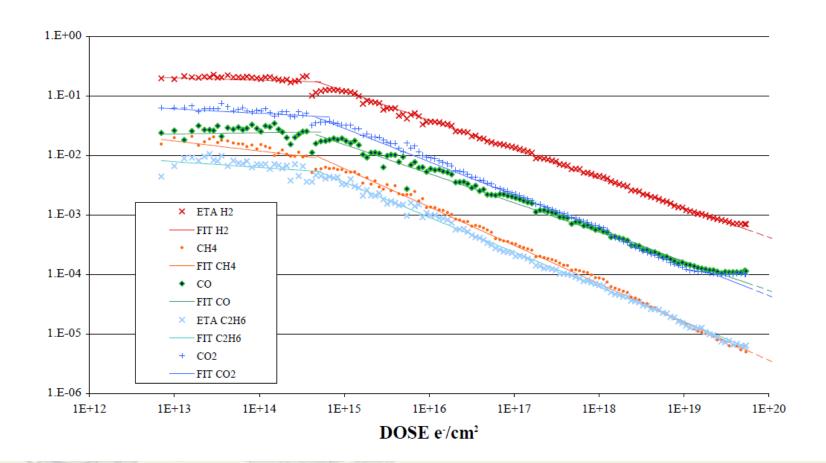




ESD data

• No much data on unbaked copper

(N. Hilleret, CAS Vacuum School 2006 - G. Vorlaufer CERN-Thesis (2002))











| | | | | Solid angle (one | | | 11 |
|----------------------|---------------------|------------------|---------------------|------------------|-----------|--------------|--------------|
| Total e- current [A] | Pulse duration [ns] | Total charge [C] | Number of electrons | cell, one side) | on copper | Dose per pul | ce (e- /cm2) |
| 1.00E-04 | 200 | 2.00E-11 | 1.25E+08 | 0.027439024 | 4.56E+09 | | 4.42E+08 |

| | ESD coefficient for H2 (unbaked copper) | Total H2 molecules | Equivalent pressure at RT (total volume) |
|-----------------------|---|-------------------------------------|--|
| G. Vorlaufer | 2.00E-01 | 9.11E+08 | 1.12E-08 |
| CERN-Thesis (2002) | ESD coefficient for CO2 (unbaked copper) | Total CO2 moiecules per KF pulse | \mathbf{X} |
| | 6.00E-02 | 2.73E+08 | 3.37E-09 |
| Benvenuti et | ESD coefficient for H2 (copper baked 250 C) | Total H2 molecules per RF pulse | |
| al LEP2 94-21 | 1.30E-02 | 5.92E+07 | 7.29E-10 |
| | ESD coefficient for CO2 (copper baked 250 C) | Total CO2 molecules per RF pulse | 01 |
| | 6.00E-03 | 2.73E+07 | 3.37E-10 |
| L al | | 1 | all bo |
| 12 | ESD coefficient for H2 (copper baked 300 C) | Total H2 molecules per RF pulse | X |
| Mathewson | 3.00E-03 | 1.37E+07 | 1.68E-10 |
| VSTA 15 1997) 3093 | ESD coefficient for CO2 (copper baked 300 C) | Total CO2 molecules per RF pulse | 12V |
| 18 | 1.60E-03 | 7.29E+06 | 8.98E-11 |

10⁷ pulses to start conditioning 10,120,000 maximum allowed 10⁹ pulses for ÷10 ESD reduction (200 days at 50 Hz) 3 times maximum allowed

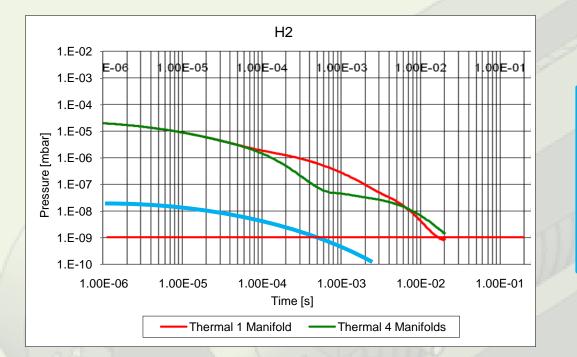
For the dynamic vacuum of breakdowns we were considering 2x10¹² molecules.





Dynamic vacuum I – Results





Pressure goes to < 10⁻⁹ mbar in less than 1 msec ! This is faster than the sampling time of common vacuum gauges...

Same plot as for dynamic vacuum due to breakdowns (2x10¹² molecules released)

Extrapolating to 1000 less molecules released due to ESD







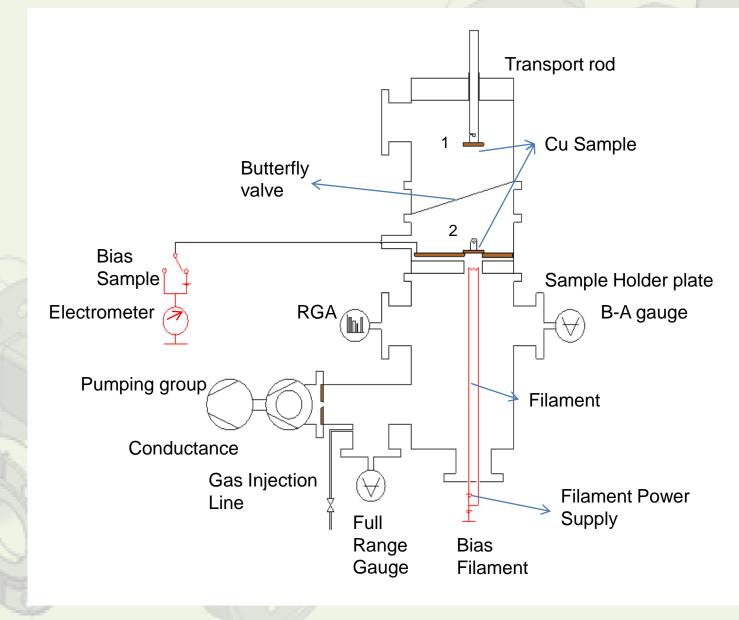
- Get more precise data on ESD: higher electron energies, effect of surface treatments and of fabrication procedure
- Obtain e⁻ trajectories maps for reasonable assumptions of distributions of field-emitters, and calibrate the intensities with known Farady-cup dark current measurements.
- Couple the above data as input for Monte-Carlo simulations of trajectories and densities of outgassed molecules





ESD measurement system





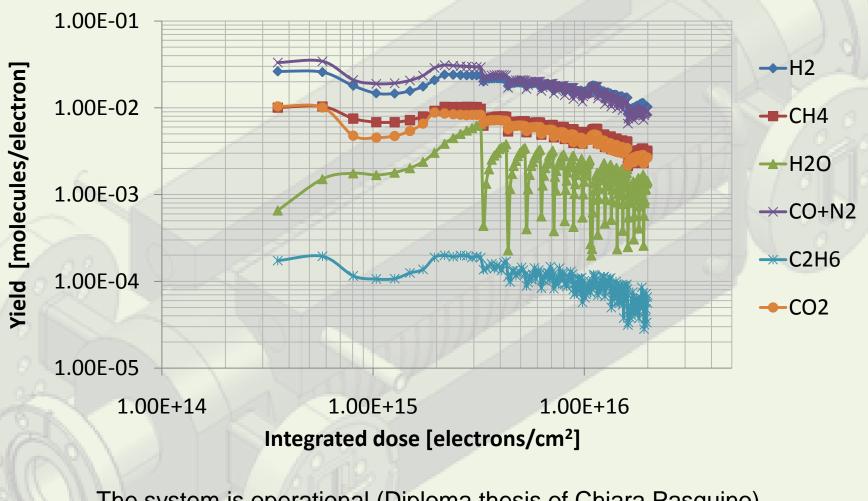






First results (dummy Cu specimen)





The system is operational (Diploma thesis of Chiara Pasquino)

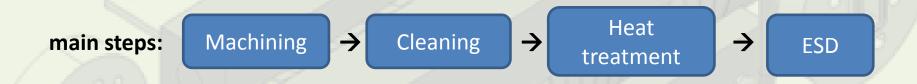




Rationale



- We want to study the effect of surface treatments and fabrication on ESD
- Large number of samples have been prepared (will be tested also by "spark-test", SEM, XPS)



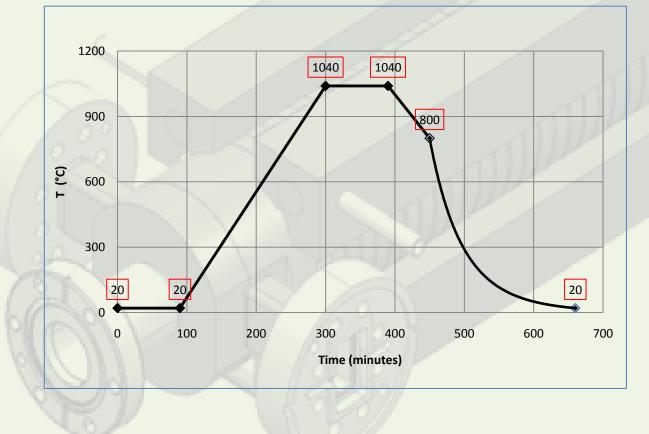
| Vacuu | m | - | | | 100 | | | | | | | | | | | 10 | | 1 | | | | | | | | | | | |
|------------|--------|--------|------|------|--------|------|------|---------|------|------|----------|------|------|----------|------|------|--------|------|------|--------|------|------|---------|-------|------|---------|--------|----|--|
| | R | EFEREN | ICE | | Vacuur | n | Arg | gon (ml | bar) | ł | -12 (mba | ar) | ŀ | l2 (1 ba | nr) | | Vacuur | n | Ar | gon (m | bar) | Hydı | rogen (| mbar) | Hyd | rogen (| 1 bar) | | |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | w/o | Passiv | SLAC | w/o | Passiv | SLAC | w/o | Passiv | SLAC | w/o | Passiv | SLAC | w/o | Passiv | SLAC | w/o | Passiv | SLAC | w/o | Passiv | SLAC | w/o | Passiv | SLAC | w/o | Passiv | SLAC | | |
| 0.5 | etch | ation | etch | etch | ation | etch | etch | ation | etch | etch | ation | etch | etch | ation | etch | etch | ation | etch | etch | ation | etch | etch | ation | etch | etch | ation | etch | | |
| CERN | 2 | 2 | 2 | 2 | 2 | 2 | | 1 | | | | | | 1 | | 2 | 2 | 2 | 2 | 2 | 2 | | | | | | | 24 | |
| | Re. | 100 | | | | | 100 | | | | | | 1 | | | | | | | | | | | | | | | | |
| Bodycote | | . `` | | | | | 2 | 2 | 2 | 2 | 2 | 2 | | | | | | | | | | 2 | 2 | 2 | | | | 18 | |
| SLAC | Sec. 1 | | N | | | | | | | 10 | | | 2 | 2 | 2 | | | | | | | | | | 2 | 2 | 4 | 14 | |
| 10 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 2 | 4 | 56 | |
| elliptical | | | | 1.00 | | | | | | | | | | | | | | | | | | | | | | | | | |







- Rationale for the calculations:
 - H₂ bonding introduces hydrogen in the copper, subsequently outgassed in vacuum annealing.
 - Any H₂ leftover may influence ESD



Bonding at 1040 °C with 1 bar of H_2

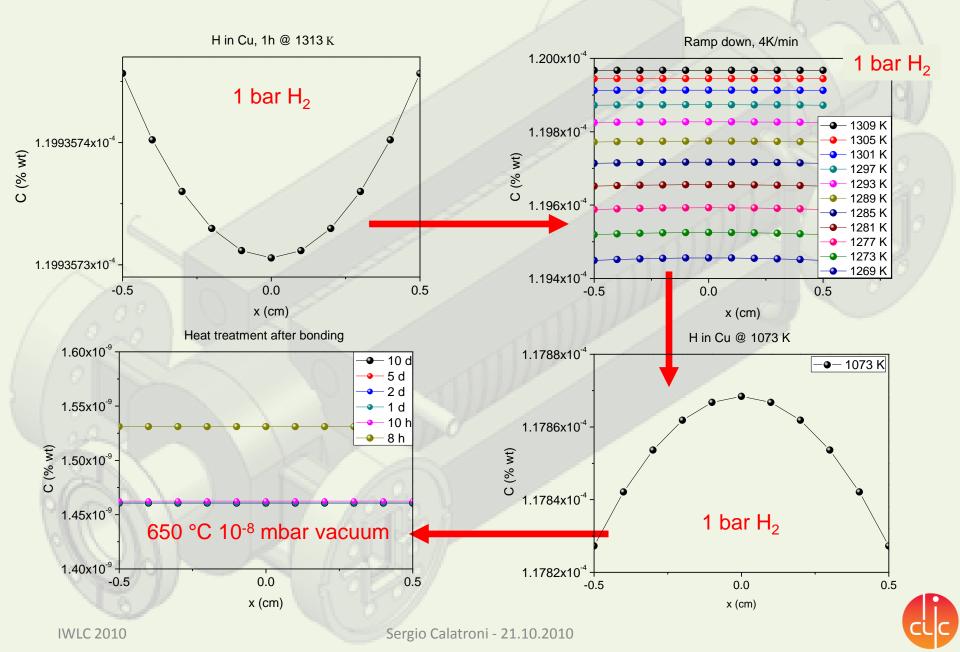
Annealing at 650 °C for 10 days 1x10⁻⁸ mbar vacuum





Calculated data (assume Cu sheet 1 cm thick)

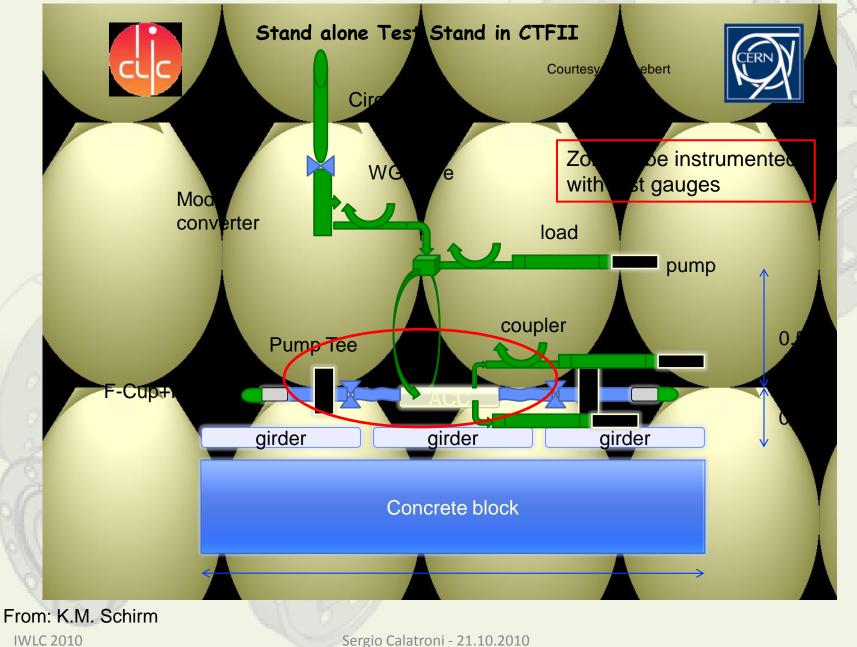






Direct measurements, anyway







Outlook 1



- Static vacuum seems to be achieved only marginally with present design
 - Need more precise data on water re-adsorption (sticking probability depends on coverage)
- Dynamic vacuum due to breakdowns seem to be under control (recovery time ≤ pulse repetition)
 - However, data from RF tests are needed for further crosschecking





Outlook 2



- Dynamic vacuum due to dark currents: still open question
- Experimental programme:
 - ESD data on unbaked copper at high e⁻ energy from CERN
 - Dark current simulations from SLAC ACE3P
 - Introduce these into MC+FEM models and get gas distribution
 - Direct measurements will be attempted in 12 GHz test bench (although feasibility is questionable)













Molecule speed



| | Atomic mass | Molecule speed | Molecule displacement in RF pulse [mm] | | | | | |
|-----|----------------|----------------|--|--|--|--|--|--|
| H2 | 2 | 1579 | 3.16E-01 | | | | | |
| Н2О | 18 | 526 | 1.05E-01 | | | | | |
| со | 28 | 422 | 8.44E-02 | | | | | |
| CO2 | 44 | 336 | 6.73E-02 | | | | | |

Assuming a molecular speed of 300 K = 0.026 eV







Tentatively crosschecked with CTF2 data + Montecarlo simulations

